

Subject card

Subject name and code	Magnetism: from fundamentals to spintronics, PG_00036987							
Field of study	Nanotechnology							
Date of commencement of studies	October 2025		Academic year of realisation of subject		2025/2026			
Education level	second-cycle studies		Subject group			Obligatory subject group in the field of study		
						Subject group related to scientific research in the field of study		
Mode of study	Full-time studies		Mode of delivery			at the university		
Year of study	1		Language of instruction			English		
Semester of study	1		ECTS credits			2.0		
Learning profile	general academic profile		Assessme	Assessment form		assessment		
Conducting unit	Institute Of Nanotechnology And Materials Engineering -> Faculty Of Applied Physics And Mathematics -> Wydziały Politechniki Gdańskiej							
Name and surname	Subject supervisor	dr hab. inż. Leszek Piotrowski						
of lecturer (lecturers)	Teachers	dr hab. inż. Leszek Piotrowski						
Lesson types and methods of instruction	Lesson type	Lecture	Tutorial	Laboratory	Projec	t	Seminar	SUM
	Number of study hours	30.0	0.0	0.0	0.0	0.0		30
	E-learning hours included: 0.0							
Learning activity and number of study hours	Learning activity	Participation in didactic classes included in study plan		Participation in consultation hours		Self-study		SUM
	Number of study hours	30		2.0		18.0		50
Subject objectives	The student learns the parameters describing and nanoscale matering possibilities of using refoundations of spintrol applications of spintrol	g the magnetic als. The studer nagnetic mater nics and practi	field. He learns at learns the m ials in practice cal ways of ma	s about the influe thods of mague. The student a anipulation of the	uence of netic pro Iso learr le spin o	magne perties s abou	etic fields on of determination t spin, theore	n and etical

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earning outcomes Course outcome		Method of verification			
[K7_W02] has enhanced, theoretically supported, detailed knowledge of selected branches of nanotechnology and, according to the needs, within the scope of related fields of science and technology.	Student knows how to describe the behaviour of spin in quantum mechanics, understand the concept of spinor and spin matrix. He also knows the problems associated with spin decoherence and manipulation of spin orientation.	[SW1] Assessment of factual knowledge			
[K7_W03] has general knowledge on current development directions and discoveries in physics, chemistry, technology and applications of nanostructures.	The student understands the principles of operation of spintronic devices. Student can explain such issues as e.g. the phenomenon of giant magnetoresistance (GMR) or the principle of operation of magnetic tunnel junctions (MTJ).	[SW1] Assessment of factual knowledge			
[K7_U01] can learn individually, obtain knowledge and integrate information from literature, databases and other properly selected sources (in Polish and English). Has the ability of critical analysis and selection of information.	Student can carry out the analysis of the available literature (on-line databases) and discuss selected issue (from the field of magnetism) described there.	[SU2] Assessment of ability to analyse information			
[K7_U07] can apply the obtained specialist knowledge to the problems within exact sciences, natural or technical sciences.		[SU2] Assessment of ability to analyse information			
1. Basic magnetic quantities2. Magnetism of atoms and molecules, atoms in external magnetic fields3. Solid state magnetism, types of magnetic materials (dia-, para-, and ferromagnetism)4. Ferromagnetism and domain structures5. Magnetism of small particles, single domain particles (StonerWohlfarth model), thin films6. Experimental techniques of magnetic properties and magnetisation state determination. Domain structurevisualisation and analysis.7. Spin transport spin polarization, spin filters, Rashba and Dresselhaus interactions8. Two currents model, spin injection and coherence length, spin dependent Hall effects.9. Magnetoresistance anisotropic magnetoresistance (AMR), gigantic magnetoresistance (GMR), tunnelling magnetoresistance (TMR) and colossal magnetoresistance (CMR). 10. Spin valves11. Magnetic data storage (HDDs)- storage media, read/write heads, construction issues.12. Spin transfer torque (STT) current induced magnetisation switching, nanooscillators13. Magnetic random access memories (MRAM), STT-MRAMS14. Spin transistors, Data and Das transistor, spin valve transistor, spin Hall effect transistor15. Magnetic logic devices Basic knowledge of quantum mechanics (Schrödinger's equation) and solid state physics (charge transportin the solid state).					
Subject passing criteria	Passing threshold	Percentage of the final grade			
written test	50.0%	100.0%			
Basic literature	Handbook of Spin Transport and Magnetism; Ed. E.Y. Tsymbal, I.Žutić; CRC Press 20122. J. Stohr, H.C. Siegmann; Magnetism From Fundamentals toNanoscale Dynamics; Springer, 2006.				
	[K7_W02] has enhanced, theoretically supported, detailed knowledge of selected branches of nanotechnology and, according to the needs, within the scope of related fields of science and technology. [K7_W03] has general knowledge on current development directions and discoveries in physics, chemistry, technology and applications of nanostructures. [K7_U01] can learn individually, obtain knowledge and integrate information from literature, databases and other properly selected sources (in Polish and English). Has the ability of critical analysis and selection of information. [K7_U07] can apply the obtained specialist knowledge to the problems within exact sciences, natural or technical sciences. 1. Basic magnetic quantities2. Magnetized domain structures5. Magnetism of stillings. Experimental techniques of not structurevisualisation and analysis. 7 interactions8. Two currents model, sexperimental techniques of not structure successistance anisotropic magnetoresistance anisotropic magnetoresistance (TMR) and colos (HDDs)- storage media, read/write has magnetisation switching, nanooscilla Spin transistors, Data and Das transidevices Basic knowledge of quantum mechathe solid state).	K7_W02 has enhanced, theoretically supported, detailed knowledge of selected branches of nanotechnology and, according to the needs, within the scope of related fields of science and technology. K7_W03 has general knowledge on current development directions and discoveries in physics, chemistry, technology and applications of nanostructures. K7_W03 has general knowledge on current development directions and discoveries in physics, chemistry, technology and applications of nanostructures. K7_U01 can learn individually, soltain knowledge and integrate information from literature, databases and other properly selected sources (in Polish and English). Has the ability of critical analysis and selection of information. K7_U07 can apply the obtained specialist knowledge to the problems within exact sciences, natural or technical sciences. Student can carry out the analysis of the available literature (on-line databases) and discuss selected sisue (from the field of magnetism) described there. Student can propose the application of magnetic magnetism of magnetic magnetism of magnetic properties and magnetism of magnetic sin other areas of science such as e.g. medicine. Student can propose the application of magnetic magnetisms of magnetic magnetisms of magnetic magnetisms of magnetic properties and magnetisation spin interactions8. Two currents model, spin injection and coherence length, structurevisualisation and analysis. 7. Spin transport spin polarization, spin interactions8. Two currents model, spin injection and coherence length, spin transistors, pagnetisms of small particles, single domain particles films6. Experimental techniques of magnetic properties and magnetisation symmetric magnetisation switching, nanooscillators 13. Magnetic random access me Spin transistors, Data and Das transistor, spin valve transistor, spin Hallidevices Subject passing criteria Passing threshold Passing threshold Passing threshold Passing threshold Passing threshold Passing threshold Pas			

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	Supplementary literature	S. Bandyopadhyay, M. Cahay; Introductioon to spintronics, CRCPress, 2008			
Example issues/	eResources addresses	Adresy na platformie eNauczanie:			
example questions/ tasks being completed	On the basis of the Biot-Savart law calculate the induction of the magnetic field in the centre of conducting loop2. Discuss the construction of spin valve3. What criteria must meet the material used for the data storage4. Discuss the phenomena causing spin coherence in solid body.5. Explain the process of spin transfer torque				
Work placement	Not applicable				

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